IN THE CLAIMS

Please amend the claims as follows:

1. (Currently Amended) A surface acoustic wave device comprising:

a plurality of transducers formed on a piezoelectric substrate including a plurality of regions, each of the regions having a pair of comb electrodes whose surface wave propagation directions are opposite to each other,

wherein at least two of the transducers are connected in parallel and opposite phase to each other and resonant modes of the transducers are coupled to prevent in-phase resonant frequency peaks from conforming to each other.

2. (Currently Amended): The surface acoustic wave device according to claim 1, wherein each of the ~~transduceres~~ transducers has a triple-mode resonant frequency characteristic.

3. (Previously Presented) A surface acoustic wave device comprising:

a plurality of transducers formed on a piezoelectric substrate including a plurality of regions, each of the regions having a pair of comb electrodes whose surface wave propagation directions are opposite to each other,

wherein at least two of the transducers are connected in parallel to each other and resonant modes of the transducers are coupled,

wherein each of the transducers has a triple-mode resonant frequency characteristic, and

wherein a first filter including one of the transducers connected in parallel has resonant frequencies of F11, Fc1 and Fu1 and a second filter including another transducer has

resonant frequencies of F12, Fc2 and Fu2, and the resonant frequencies are expressed as follows:

$$F11 < F12 < Fc2 < Fc1 < Fu1 < Fu2.$$

4. (Previously Presented) A surface acoustic wave device comprising:

a plurality of transducers formed on a piezoelectric substrate including a plurality of regions, each of the regions having a pair of comb electrodes whose surface wave propagation directions are opposite to each other,

wherein at least two of the transducers are connected in parallel to each other and resonant modes of the transducers are coupled,

wherein each of the transducers has a triple-mode resonant frequency characteristic, and

wherein a first filter including one of the transducers connected in parallel has resonant frequencies of F11, Fc1 and Fu1 and a second filter including another transducer has resonant frequencies of F12, Fc2, and Fu2, a phase of the resonant frequency F11 is opposite to that of the resonant frequency F12, a phase of the resonant frequency Fc1 is opposite to that of the resonant frequency Fc2, and a phase of the resonant frequency Fu1 is opposite to that of the resonant frequency Fu2.

5. (Previously Presented) A surface acoustic wave device comprising:

a plurality of transducers formed on a piezoelectric substrate including a plurality of regions, each of the regions having a pair of comb electrodes whose surface wave propagation directions are opposite to each other,

wherein at least two of the transducers are connected in parallel to each other and resonant modes of the transducers are coupled,

wherein each of the transducers has a triple-mode resonant frequency characteristic, and

wherein a first filter including one of the transducers connected in parallel has resonant frequencies of F11, Fc1 and Fu1 and a second filter including another transducer has resonant frequencies of F12, Fc2 and Fu2, and respective intervals of at least four resonant frequencies are substantially equal to each other.

6. (Previously Presented) A surface acoustic wave device comprising:

a plurality of transducers formed on a piezoelectric substrate including a plurality of regions, each of the regions having a pair of comb electrodes whose surface wave propagation directions are opposite to each other,

wherein at least two of the transducers are connected in parallel to each other and resonant modes of the transducers are coupled,

wherein each of the transducers has a triple-mode resonant frequency characteristic, and

wherein a first filter including one of the transducers connected in parallel has resonant frequencies of F11, Fc1 and Fu1 and a second filter including another transducer has resonant frequencies of F12, Fc2 and Fu2, and insertion losses of at least four of the resonant frequencies are substantially equal to each other.

7. (Currently Amended): The surface acoustic wave device according to claim 1, wherein one of the ~~transudcers~~ transducers connected in parallel and another ~~transudcer~~ transducer are formed on a single chip.

8. (Original): The surface acoustic wave device according to claim 1, wherein one of the transducers connected in parallel and another transducer are formed on different chips.